

SQM200N04-1M1L_GE3

SQM200N04-1M1L_GE3 Information



Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



SQM200N04-1M1L_GE3 Specifications

Manufacturer Part Number	SQM200N04-1M1L_GE3
Manufacturer	Vishay Siliconix
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-263-7, D2Pak (6 Leads + Tab)
Series	TrenchFET?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	40V
Current - Continuous Drain (Id) @ 25°C	200A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs(th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	413nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	20655pF @ 25V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	375W (Tc)
Rds On (Max) @ Id, Vgs	1.1 mOhm @ 30A, 10V
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	TO-263-7
Package / Case	TO-263-7, D2Pak (6 Leads + Tab)
	Report errors?

SQM200N04-1M1L_GE3 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.



If you have any question about SQM200N04-1M1L_GE3, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com